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## High Voltage LED Series Chip on Board

# LC026B



# High efficacy COB LED package well-suited for use in spotlight applications

#### **Features & Benefits**

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability
- Completed 6,000 hours of LM-80 Testing
- ENEC certified: Integral LED Module

#### **Applications**

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination











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#### 1. Characteristics

#### a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	°C	-
Storage Temperature	$T_{stg}$	-40 ~ +120	°C	-
LED Junction Temperature	Tj	150	°C	-
Case Temperature	Тс	105	°C	*Note
Forward Current	l <sub>F</sub>	1300	mA	-
Power Dissipation	$P_{D}$	48.1	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

#### b) Electro-optical Characteristics (I<sub>F</sub> = 720 mA, $T_a$ = 25 °C)

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V <sub>F</sub> )	V	YH	32.5	35.5	38.5
		3	70	-	-
Color Dandaring Inday (D.)		5	80	-	-
Color Rendering Index (R <sub>s</sub> )	-	7	90	-	-
		8	95		
Thermal Resistance (junction to chip point)	°C/W		-	0.9	_
Beam Angle	o		-	115	-
Working Voltage for Insulation	V				50
Nominal Power	W			25.6	
Eye Protection		Risk 1	_		-

#### Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_i = T_c = T_a = 25$  °C)
- 2) Samsung maintains measurement tolerance of: forward voltage =  $\pm 5$  %, CRI =  $\pm 1$
- 3) Max Tc=105°C (at max current) is for ENEC condition. Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.



#### c) Luminous Flux Characteristics (I<sub>F</sub> = 720 mA)

CRI (R <sub>a</sub> )	Nominal	Flux	Flux	Sorting <sup>1)</sup> @	$T_c = 25 ^{\circ}\text{C (Im)}$	Calculated Flux <sup>2)</sup> @ T <sub>o</sub>	= 85 °C (lm)
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
	3000	3F	31	3266	3711	2939	3340
	3000	SF	32	3711	4157	3340	3741
70	4000	٥٦	31	3429	3897	3086	3507
70	4000	3F	32	3897	4365	3507	3928
	5000	٥٦	31	3462	3934	3116	3541
	5000	3F	32	3934	4406	3541	3965
			28	2710	2920	2466	2657
			29	2920	3130	2657	2848
		2F	30	3130	3340	2848	3039
	2700		31	3340	3550	3039	3231
			32	3550	3760	3231	3422
			31	3340	3550	3039	3231
		2G	32	3550	3760	3231	3422
			28	2890	3110	2630	2830
			29	3110	3330	2830	3030
		2F	30	3330	3550	3030	3231
	3000		31	3550	3770	3231	3431
			32	3770	3990	3431	3631
			31	3550	3770	3231	3431
80		2G	32	3770	3990	3431	3631
			28	3000	3220	2730	2930
			29	3220	3440	2930	3130
		2F	30	3440	3660	3130	3331
	3500		31	3660	3880	3331	3531
			30	3440	3660	3130	3331
		2G	31	3660	3880	3331	3531
			28	3080	3310	2803	3012
			29	3310	3540	3012	3221
		2F	30	3540	3770	3221	3431
	4000		31	3770	4000	3431	3640
			30	3540	3770	3221	3431
		2G	31	3770	4000	3431	3640



#### c) Luminous Flux Characteristics (I<sub>F</sub> = 720 mA)

CRI (R <sub>a</sub> )	Nominal	Flux	Flux	Sorting <sup>1)</sup> @ <sup>-</sup>	$T_c = 25 ^{\circ}\text{C (Im)}$	Calculated Flux <sup>2)</sup>	@ T <sub>c</sub> = 85 °C (lm)
Min.	CCT (K)	Rank	Bin	Min.	Max.	Min.	Max.
			32	3130	3360	2848	3058
		0.5	33	3360	3590	3058	3267
	5000	3F	34	3590	3820	3267	3476
	5000		35	3820	4050	3476	3686
		00	34	3590	3820	3267	3476
00		2G	35	3820	4050	3476	3686
80			32	3130	3360	2848	3058
		0.5	33	3360	3590	3058	3267
	5700	3F	34	3590	3820	3267	3476
	5700		35	3820	4050	3476	3686
		00	34	3590	3820	3267	3476
		2G	35	3820	4050	3476	3686
			21	2110	2345	1920	2134
	2700	0.5	22	2345	2580	2134	2348
		2F	23	2580	2815	2348	2562
			24	2815	3050	2562	2776
			21	2150	2390	1957	2175
		0.5	22	2390	2630	2175	2393
	3000	2F	23	2630	2870	2393	2612
00			24	2870	3110	2612	2830
90			21	2220	2465	2020	2243
	0500	0.5	22	2465	2710	2243	2466
	3500	2F	23	2710	2955	2466	2689
			24	2955	3200	2689	2912
			21	2285	2535	2079	2307
	4000	0.5	22	2535	2785	2307	2534
	4000	2F	23	2785	3035	2534	2762
			24	3035	3285	2762	2989
	0700	0.5	21	2321	2578	2112	2346
	2700	2F	22	2578	2836	2346	2581
OF	0000	0.5	21	2392	2658	2177	2419
95	3000	2F	22	2658	2924	2419	2661
	0500	0.5	21	2440	2711	2221	2467
	3500	2F	22	2711	2983	2467	2714

#### Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_j = T_c = T_a = 25$  °C)
- 2) Calculated flux values are for reference only
- 3) Samsung maintains measurement tolerance of: luminous flux =  $\pm 7$  %, CRI =  $\pm 1$



#### 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	н	С	w	1	н	D	N	С	2	5	Υ	н	R	т	3	F

Digit	PKG Information	Code				Specificat	ion	
1 2 3	Samsung Package High Power	SPH						
4.5	0.1	ww	Warm White	(T/U/	V/W Rank	(S)		
4 5	Color	cw	Cool White	(Q/R	Ranks)			
6	Product Version	1						
7 8	Form Factor	HD	СОВ					
9	Lens Type	N	No lens					
10	Internal Code	С	LC026					
11	Chip Type	2						
		3	Min. 70					
12	CRI & Sorting Temperature	5	Min. 80 2	5°C				
	or in a cortaing remperature	7	Min. 90					
		8	Min 95					
13 14	Forward Voltage (V)	YH	32.5~38.5					
		W	2700 K		WA,WB	(MacAdam Ellipse)		
		V	3000 K		VA, VB	(MacAdam Ellipse)	VW, VX, VY, VZ (ANSI bin)	
15	CCT (K)	U	3500 K	Bin	UA, UB	(MacAdam Ellipse)		
		Т	4000 K	Code:	TA, TB	(MacAdam Ellipse)	TW, TX, TY, TZ (ANSI bin)	
		R	5000 K		RA	(MacAdam Ellipse)	RW, RX, RY, RZ (ANSI bin)	
		Q	5700 K				QW, QX, QY, QZ (ANSI bin)	
		2	MacAdam 2	-step				
16	MacAdam / ANSI	3	MacAdam 3	-step				
		Т	ANSI bin					
		2F		Di	21, 22 (95	5 CRI) 21, 22, 23, 24 (90	CRI); 28, 29, 30, 31, 32 (80 CRI),	
17 18	Luminous Flux	2G	2G Bin Code: 31, 32 (80 CRI) 30, 31 (80 CRI) 34, 35 (80 CRI),					
		3F			32, 33, 34	4, 35 (80 CRI); 31, 32 (7	70 CRI)	



#### a) Binning Structure (I<sub>F</sub> = 720 mA, T<sub>c</sub> = 25 °C)

CRI (R₃) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ <sub>v</sub> , lm)				
	2000		VII	\/T	VW, VX	٥٦	31	3266 ~ 3711				
	3000	SPHWW1HDNC23YHVT3F	YH	VT	VY, VZ	3F	32	3711 ~ 4157				
70	4000	SPHWW1HDNC23YHTT3F	VII	<del></del>	TW, TX	3F	31	3429 ~ 3897				
70	4000	SPHWWINDING231H113F	YH	π	TY, TZ	3F	32	3897 ~ 4365				
	5000	SPHCW1HDNC23YHRT3F	ΥH	RT	RW, RX	3F	31	3462 ~ 3934				
	3000	OF FIGW HIDNOZOTTITTO	111	111	RY, RZ	01	32	3934 ~ 4406				
							28	2710 ~ 2920				
							29	2920 ~ 3130				
		SPHWW1HDNC25YHW22F	YH	W2	WB	2F	30	3130 ~ 3340				
							31	3340 ~ 3550				
							32	3550 ~ 3760				
							28	2710 ~ 2920				
	2700						29	2920 ~ 3130				
		SPHWW1HDNC25YHW32F	ΥH	W3	WA, WB	2F	30	3130 ~ 3340				
							31	3340 ~ 3550				
							32	3550 ~ 3760				
					SPHWW1HDNC25YHW22G	THW22G YH W2 WB 2G	2G	31	3340 ~ 3550			
							32	3550 ~ 3760				
							SPHWW1HDNC25YHW32G	ΥH	W3	WA, WB	2G	31
80							32	3550 ~ 3760				
							28	2890 ~ 3110				
							29	3110 ~ 3330				
		SPHWW1HDNC25YHV22F	ΥH	V2	VB	2F	30	3330 ~ 3550				
							31	3550 ~ 3770				
							32	3770 ~ 3990				
							28	2890 ~ 3110				
	3000						29	3110 ~ 3330				
	0000	SPHWW1HDNC25YHV32F	YH	V3	VA, VB	2F	30	3330 ~ 3550				
							31	3550 ~ 3770				
							32	3770 ~ 3990				
		SPHWW1HDNC25YHV22G	ΥH	V2	VB	2G	31	3550 ~ 3770				
		OT TIWWW ITIDINOZOTTIVZZO	111	٧٧	V D	29	32	3770 ~ 3990				
		SPHWW1HDNC25YHV32G	ΥH	V3	VA, VB	2G	31	3550 ~ 3770				
		OF THAM A HIDINOZOTTIVOZO	111	٧٥	v., v.	20	32	3770 ~ 3990				



#### a) Binning Structure (I<sub>F</sub> = 720 mA, T<sub>c</sub> = 25 °C)

CRI (R₃) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ <sub>v</sub> , lm)
							28	3000 ~ 3220
		SPHWW1HDNC25YHU22F	ΥH	U2	UB	2F	29	3220 ~ 3440
		SPHWWINDING231HUZZF	TП	02	UВ	25	30	3440 ~ 3660
							31	3660 ~ 3880
							28	3000 ~ 3220
	3500	SPHWW1HDNC25YHU32F	ΥH	U3	UA, UB	2F	29	3220 ~ 3440
	3300	SPHWWINDING231H032F	TH	03	UA, UB	25	30	3440 ~ 3660
							31	3660 ~ 3880
		SPHWW1HDNC25YHU22G	VLI	U2	UB	20	30	3440 ~ 3660
		SPHWW INDINO231HUZZG	YH	UZ	UB	2G -	31	3660 ~ 3880
		SPHWW1HDNC25YHU32G	ΥH	U3	IIA IID	20	30	3440 ~ 3660
		SPHWWINDING231HU32G	TП	US	UA, UB	2G	31	3660 ~ 3880
							28	3080 ~ 3310
		SPHWW1HDNC25YHT22F	ΥH	TO	TD	2F	29	3310 ~ 3540
		SPHWW IHDING25 ( H 122F	ΥH	T2	TB	2F '	30	3540 ~ 3770
							31	3770 ~ 4000
							28	3080 ~ 3310
	4000	ODLIMANALIDA OCCIVILIZACE	ΥH	Το.	TA TD	2E	29	3310 ~ 3540
	4000	SPHWW1HDNC25YHT32F	ΥH	T3	TA, TB	2F	30	3540 ~ 3770
							31	3770 ~ 4000
00							30	3540 ~ 3770
80		SPHWW1HDNC25YHT22G	YH	T2	TB	2G	31	3770 ~ 4000
			N/11		T. T.		30	3540 ~ 3770
		SPHWW1HDNC25YHT32G	ΥH	T3	TA, TB	2G	31	3770 ~ 4000
							32	3130 ~ 3360
		00110144110110057110005	VIII	DO	Β.		33	3360 ~ 3590
		SPHCW1HDNC25YHR33F	ΥH	R3	RA	3F	34	3590 ~ 3820
							35	3820 ~ 4050
							32	3130 ~ 3360
					RW, RX,		33	3360 ~ 3590
	5000	SPHCW1HDNC25YHRT3F	ΥH	RT	RY, RZ	3F	34	3590 ~ 3820
							35	3820 ~ 4050
		0.000.000.000					34	3590 ~ 3820
		SPHCW1HDNC25YHR32G	YH	R3	RA	2G	35	3820 ~ 4050
	***	0011011411211005			RW, RX,		34	3590 ~ 3820
		SPHCW1HDNC25YHRT2G	YH	RT	RY, RZ	2G	35	3820 ~ 4050
							32	3130 ~ 3360
					QW, QX		33	3360 ~ 3590
		SPHCW1HDNC25YHQT3F	YH	QT	QY, QZ	3F	34	3590 ~ 3820
	5700						35	3820 ~ 4050
	***				QW, QX		34	3590 ~ 3820
		SPHCW1HDNC25YHQT2G	ΥH	QT	QY, QZ	2G	35	3820 ~ 4050



#### a) Binning Structure (I<sub>F</sub> = 720 mA, $T_{\circ}$ = 25 °C)

CRI (R <sub>a</sub> ) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Ф <sub>v</sub> , lm)
							21	2110 ~ 2345
		SPHWW1HDNC27YHW22F	ΥH	W2	WB	2F -	22	2345 ~ 2580
		OF THWW ITIDINOZ/TTIWZZI	111	VVZ	VVD	۳.	23	2580 ~ 2815
	2700						24	2815 ~ 3050
	2100						21	2110 ~ 2345
		SPHWW1HDNC27YHW32F	ΥH	W3	WA, WB	2F -	22	2345 ~ 2580
		SEUMMIUDIOZI IUMSZE	TH	VVS	WA, WD	۷۲	23	2580 ~ 2815
							24	2815 ~ 3050
							21	2150 ~ 2390
		ODLIMMALIDNICOZVI IVOOF	VII	\/O	V/D		22	2390 ~ 2630
		SPHWW1HDNC27YHV22F	YH	V2	VB	2F -	23	2630 ~ 2870
	0000						24	2870 ~ 3110
	3000						21	2150 ~ 2390
							22	2390 ~ 2630
		SPHWW1HDNC27YHV32F	ΥH	V3	VA, VB	2F -	23	2630 ~ 2870
							24	2870 ~ 3110
90					21	2220 ~ 2465		
				U2	UB		22	2465 ~ 2710
		SPHWW1HDNC27YHU22F	ΥH			2F -	23	2710 ~ 2955
							24	2955 ~ 3200
	3500						21	2220 ~ 2465
							22	2465 ~ 2710
		SPHWW1HDNC27YHU32F	YH	U3	UA, UB	2F -	23	2710 ~ 2955
							24	2955 ~ 3200
							21	2285 ~ 2535
							22	2535 ~ 2785
		SPHWW1HDNC27YHT22F	ΥH	T2	ТВ	2F -	23	2785 ~ 3035
							24	3035 ~ 3285
	4000						21	2285 ~ 2535
							22	2535 ~ 2785
		SPHWW1HDNC27YHT32F	ΥH	T3	TA, TB	2F -	23	2785 ~ 3035
							24	3035 ~ 3285

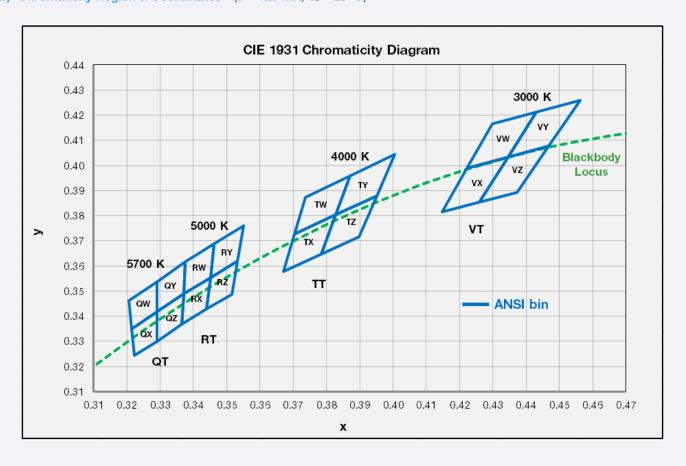


#### a) Binning Structure (I<sub>F</sub> = 720 mA, T<sub>c</sub> = 25 °C)

CRI (R <sub>a</sub> ) Min.	Nominal CCT (K)	Product Code	V <sub>F</sub> Rank	Color Rank	Chrom. Bin	Flux Rank	Flux Bin	Flux Range (Φ <sub>ν</sub> , lm)
		SPHWW1HDNC28YHW22F	ΥH	W2	WB	2F ·	21	2321 ~ 2578
	2700	SPRWWINDINGZOTRWZZP	TП	VVZ	VVD	ZF .	22	2578 ~ 2836
		SPHWW1HDNC28YHW32F			WA,WB	2F ·	21	2321 ~ 2578
		SENVIVI INDINGZOT NIVSZE	YH	W3	VVA,VVD	2	22	2578 ~ 2836
		SPHWW1HDNC28YHV22F	ΥH	V2	VB	2F	21	2392 ~ 2658
95	3000	SFTIWWWTHIDINO20111V221	111	٧Z	<b>V</b> D	۷.	22	2658 ~ 2924
93	3000	SPHWW1HDNC28YHV32F	ΥH	V3	VA,VB	2F ·	21	2392 ~ 2658
		SFIIWWIIIDNO20111V321	111	V3	VA,VB	21	22	2658 ~ 2924
		SPHWW1HDNC28YHU22F	ΥH	U2	UB	2F ·	21	2440 ~ 2711
	3500	SEUMMINDINGZOT HOZZE	TH	02	OB	2Γ	22	2711 ~ 2983
	3300	SPHWW1HDNC28YHU32F	ΥH	U3	UA,UB	2F ·	21	2440 ~ 2711
		3F118888 111DNO201 F1032F	111	03	UA,UB	<u>دا</u>	22	2711 ~ 2983



#### b) Chromaticity Region & Coordinates (I<sub>F</sub> = 720 mA, $T_a$ = 25 °C)

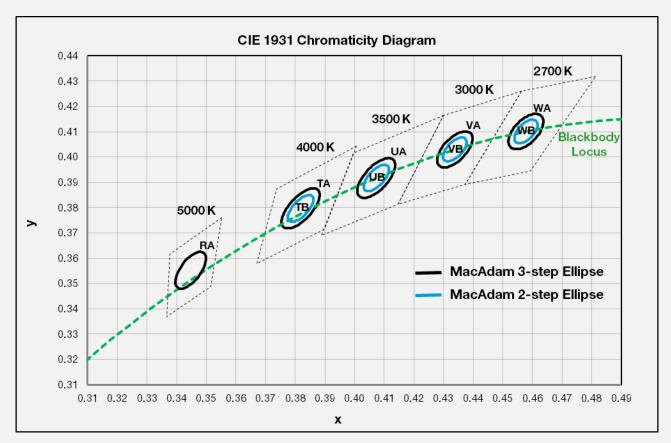


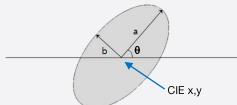
Region	CIE x	CIE y	Region	CIE x	CIE y
		V rank	(3000 K)	•	
	0.4223	0.399		0.4345	0.4033
VW	0.4345	0.4033	VY	0.4468	0.4077
VVV	0.4431	0.4213	VI	0.4562	0.4260
	0.4299	0.4165		0.4431	0.4213
	0.4223	0.399		0.4260	0.3854
VX	0.4147	0.3814	V7	0.4373	0.3893
٧٨	0.4260	0.3854	٧Z	0.4468	0.4077
	0.4345	0.4033		0.4345	0.4033
		R rank	(5000 K)		
	0.3376	0.3616		0.3463	0.3687
DW	0.3463	0.3687	D)/	0.3551	0.3760
RW	0.3451	0.3554	RY	0.3533	0.3620
	0.3371	0.3490		0.3451	0.3554
	0.3371	0.3490		0.3451	0.3554
DV	0.3451	0.3554	DZ	0.3533	0.3620
RX	0.3440	0.3428	RZ	0.3515	0.3487
	0.3366	0.3369		0.3440	0.3428

Region	CIE x	CIE y	Region	CIE x	CIE y				
	T rank (4000 K)								
	0.3736	0.3874		0.3871	0.3959				
TW	0.3871	0.3959	TY	0.4006	0.4044				
IVV	0.3828	0.3803	11	0.3952	0.388				
	0.3703	0.3726	5	0.3828	0.3803				
	0.3703	0.3726		0.3828	0.3803				
TX	0.3828	0.3803	TZ	0.3952	0.388				
1.	0.3784	0.3647		0.3898	0.3716				
	0.367	0.3578		0.3784	0.3647				
		Q rank	(5700 K)						
	0.3207	0.3462		0.3290	0.3538				
QW	0.3290	0.3538	QY	0.3376	0.3616				
QVV	0.3290	0.3417	QT	0.3371	0.3490				
	0.3215	0.3350		0.3290	0.3417				
	0.3215	0.3350		0.3290	0.3417				
QX	0.3290	0.3417	QZ	0.3371	0.3490				
QX	0.3290	0.3300	QZ	0.3366	0.3369				
	0.3222	0.3243		0.3290	0.3300				



#### b) Chromaticity Region & Coordinates (I<sub>F</sub> = 720 mA, $T_a$ = 25 °C)





MacAdam Ellipse (WA, WB)							
Step CIE x CIE y θ a							
2-step	0.4578	0.4101	53.70	0.0054	0.0028		
3-step	0.4578	0.4101	53.70	0.0081	0.0042		

MacAdam Ellipse (UA, UB)							
Step CIE x CIE y θ a b							
2-step	0.4073	0.3917	54.00	0.0062	0.0028		
3-step 0.4073 0.3917 54.00 0.0093 0.0041							

MacAdam Ellipse (RA)							
Step CIE x CIE y θ a b							
3-step 0.3447 0.3553 59.62 0.0082 0.0035							

MacAdam Ellipse (VA, VB)							
Step CIE x CIE y θ a b							
2-step	0.4338	0.403	53.22	0.0056	0.0027		
3-step	3-step 0.4338 0.4030 53.22 0.0083 0.004						

MacAdam Ellipse (TA, TB)								
Step	Step CIE x CIE y θ a b							
2-step	0.3818	0.3797	53.72	0.0063	0.0027			
3-step 0.3818 0.3797 53.72 0.0094 0.0040								

#### Note:

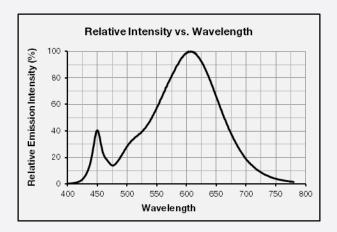
Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 



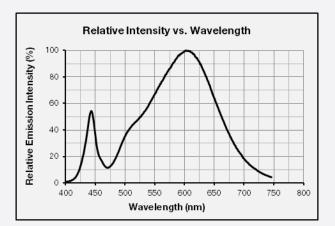
#### 3. Typical Characteristics Graphs

#### a) Spectrum Distribution ( $I_F = 720 \text{ mA}, T_a = 25 ^{\circ}\text{C}$ )

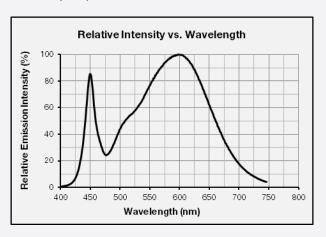
CCT: 2700 K (80 CRI)



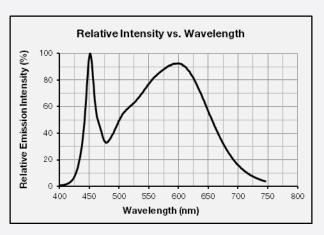
CCT: 3000 K (80 CRI)



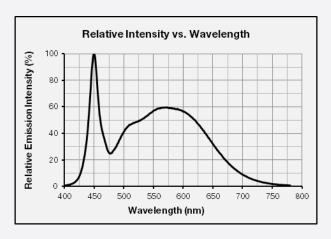
CCT: 3500 K (80 CRI)



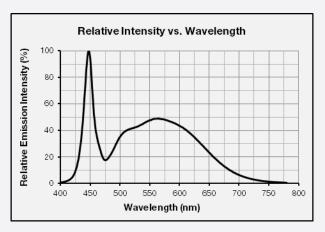
CCT: 4000 K (80 CRI)



CCT: 5000 K (80 CRI)



CCT: 5700 K (80 CRI)

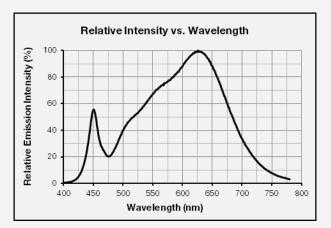




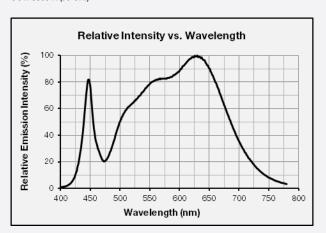
CCT: 2700 K (90 CRI)

# Relative Intensity vs. Wavelength 80 40 40 40 40 450 500 550 600 650 700 750 800 Wavelength (nm)

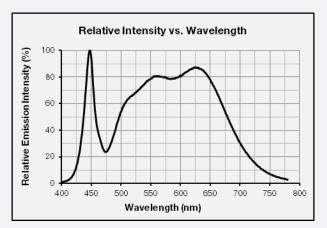
CCT: 3000 K (90 CRI)



CCT: 3500 K (90 CRI)

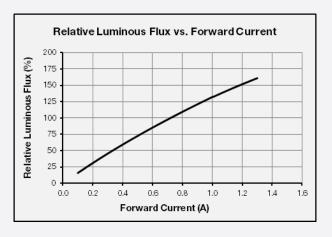


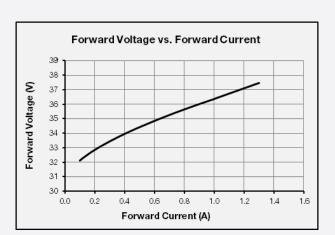
CCT: 4000 K (90 CRI)



#### b) Forward Current Characteristics (T<sub>a</sub> = 25 °C)

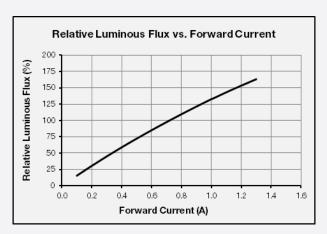
80 CRI

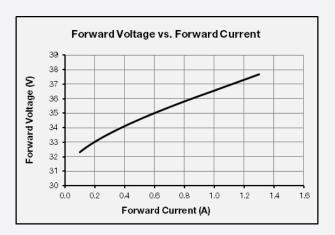






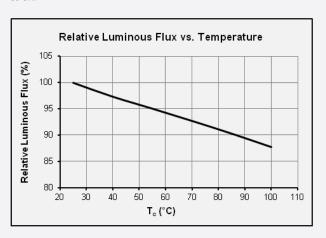
90 CRI

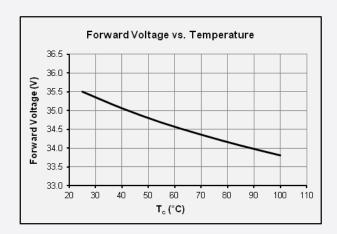




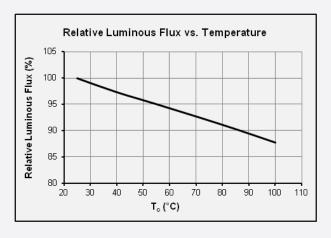
#### c) Temperature Characteristics (I<sub>F</sub> = 720 mA)

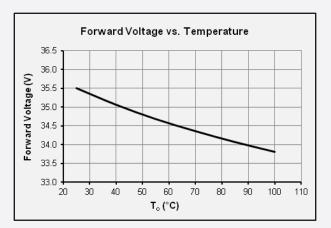
80 CRI





90 CRI





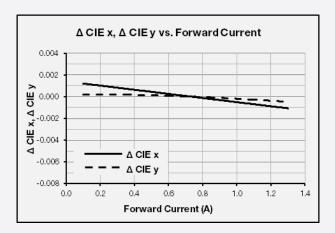


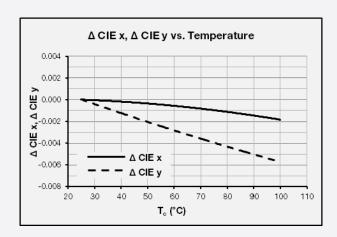
#### d) Color Shift Characteristics

T<sub>a</sub> = 25 °C

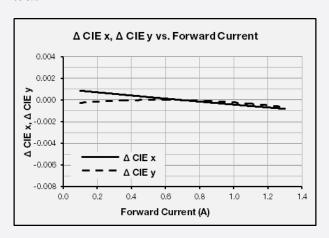
I<sub>F</sub> = 720 mA

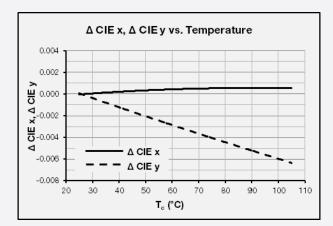
80 CRI



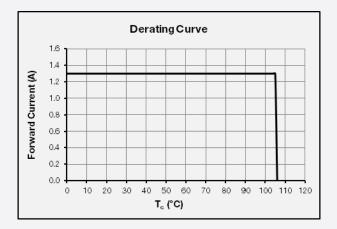


90 CRI





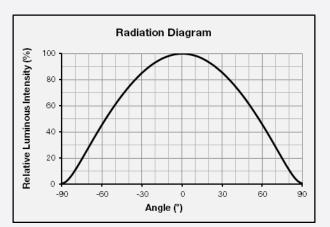
#### e) Derating Curve



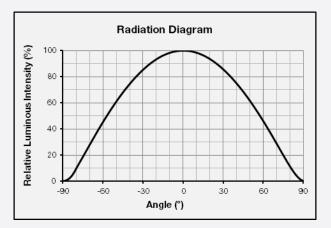


#### f) Beam Angle Characteristics (I<sub>F</sub> = 720 mA, T<sub>a</sub> = 25 °C)

80 CRI

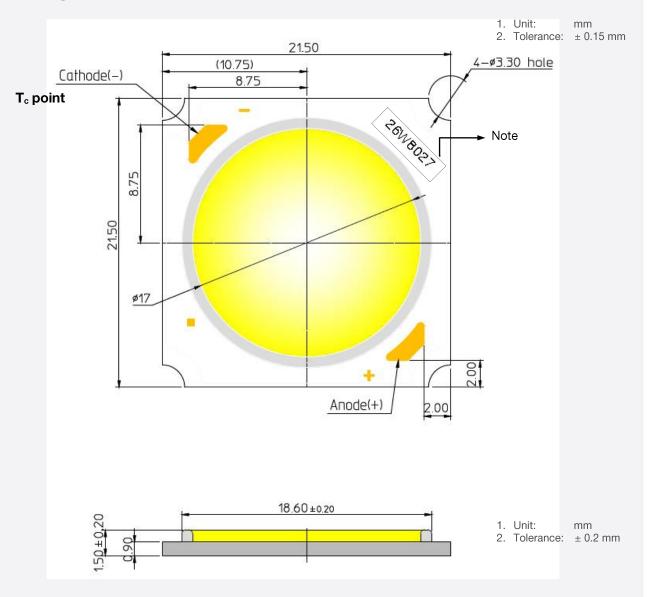


90 CRI





#### 4. Outline Drawing & Dimension



ltem	Dimension	Tolerance	Unit
Length	21.50	±0.15	mm
Width	21.50	±0.15	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	17	±0.15	mm

Note: Denoted product information above is only an example

(26W8027:26W, CRI80+, 2700K)



### 5. Reliability Test Items & Conditions

#### a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, I <sub>F</sub> = max	1000 h
High Temperature Humidity Life Test	85 °C, 85 % RH, DC Derating, $I_F$ = max	1000 h
High Temperature Life Test	105 °C, DC Derating, I <sub>F</sub> = max	1000 h
Low Temperature Life Test	-40 °C, DC 1300 mA	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Thermal Shock	-45 °C / 15 min ↔ 125 °C / 15 min temperature change in 5 min	200 cycles
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, DC 720 mA	100 cycles
Temperature Humidity Storage Test	-10 °C ↔ 25 °C, 95 % RH ↔ 85 °C, 95 % RH (24 h / cycle)	100 cycles
ESD (HBM)	R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 1.5 kΩ C: 100 pF V: ±2 kV	5 times
ESD (MM)	$R_{1}$ : $10~M\Omega$ $R_{2}$ : $0~k\Omega$ $C$ : $200~pF$ $V$ : $\pm 0.5~kV$	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Salt Spray Test	35 °C, 5 % salt water 8 h spray, 16 h dwell	2 cycles

#### b) Criteria for Judging the Damage

ltem	Symbol	Symbol Test Condition		Limit		
item	Зушоог	(T <sub>c</sub> = 25 °C)	Min.	Max.		
Forward Voltage	VF	$I_F = 720 \text{ mA}$	L.S.L. * 0.9	U.S.L. * 1.1		
Luminous Flux	$\Phi_{\scriptscriptstyle V}$	I <sub>F</sub> = 720 mA	L.S.L * 0.7	U.S.L * 1.3		



#### 6. Label Structure

#### a) Label Structure

#### **Aluminum Bag & Inner Box Outer Box** $@ \ b \ c \ d \ e \ f$ YHRW33 **YHRW33** Rank SPHCW1HDNC25YHRT3F YHRW33 01 SPHCW1HDNC25YHRT3F YHRW33 01 Code ●◎◇◆□■△△△//A▲▲/ XXX PCS Lot number OEB1906001/40 OEB1906001/40 OEB1906011/40 OEB1906002/40 OEB1906002/40 OEB1906012/40 OEB1906003/40 OEB1906013/40 Tray OEB1906003/40 number OEB1906004/40 OEB1906004/40 /Q'ty OEB1906005/40 OEB1906005/40 OEB1906006/40 OEB1906007/40 OEB1906008/40 OEB1906009/40 OEB1906010/40 SAMSUNG SAMSUNG [Box Label]

Note: Denoted rank code and product code above is only an example (see description on page 6)

#### Rank Code:

(refer to page 7-10)

© d: Chromaticity bin (refer to page 12-12)

(refer to page 7-10)



#### b) Lot Number

The lot number is composed of the following characters:

#### ● ◎ ◇ ◆ □ ■ △ △ △ / 1 ▲ ▲ ▲ / xxx PCS

• : Production site (S: Giheung, Korea, G: Tianjin, China)

○ : L (LED)

: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

• Year (Y: 2014, Z: 2015, A: 2016, ...)

□ : Month (1~9, A, B, C)■ : Day (1~9, A, B~V)

 $\triangle \triangle \triangle$  : Product serial number (001 ~ 009)

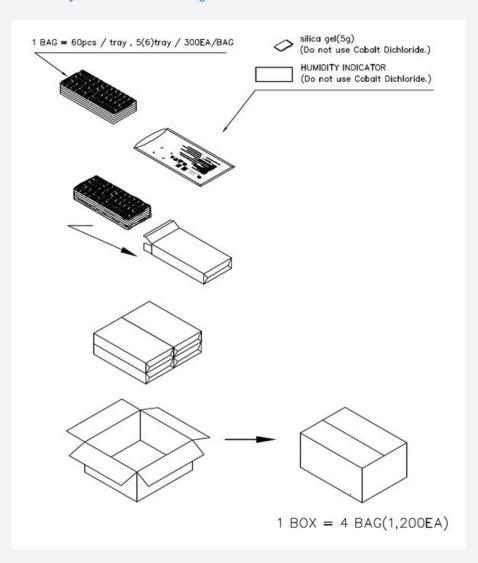
**▲ ▲**  : Tray number (001 ~ 999)



#### 7. Packing Structure

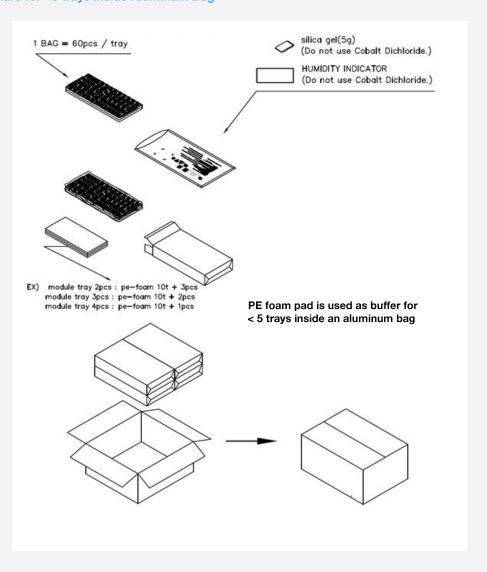
Dealting makerial	Max. quantity	Dimension (mm)				
Packing material	in pcs of COB	Length	Width	Height	Tolerance	
Tray	60	322.6	135.9	11	0.25	
Aluminum Bag	300 (5 trays)	450	230	-	10	
PE Foam Pad	-	280	130	10	2	
Inner Box	300 (1 aluminum bag)	338	148	55	2	
Outer Box	1200 (4 inner boxes)	351	308	120	5	
Pallet	67,200 (56 outer boxes)	1000	1000	970	10	

#### a) Packing Structure for 5 trays inside Aluminum Bag

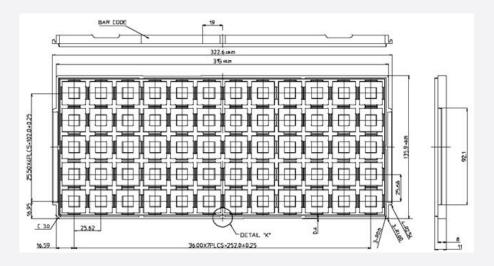




#### b) Packing Structure for <5 trays inside Aluminum Bag

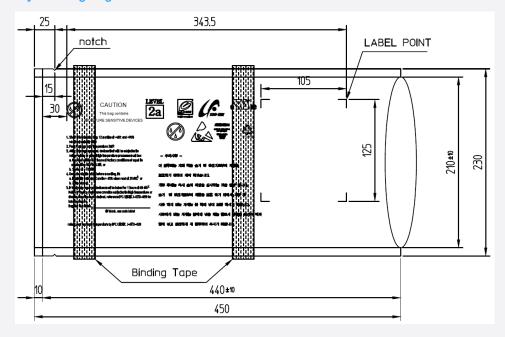


#### c) Tray



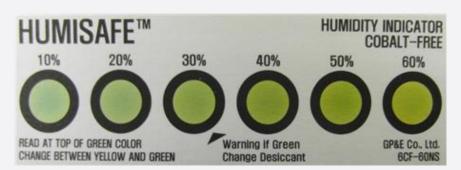


#### d) Aluminum Vinyl Packing Bag



#### e) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Packing Bag







#### 8. Precautions in Handling & Use

- 1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at  $60 \pm 5$  °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 9) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.

